

# Optimising the design of small pitch Hybrid Pixel Detectors with MÖNCH04

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# JUNGFRAU0.1

#### MÖNCH01

6 Test structures on JUNGFRAU0.1 → Technology performance assessment → Base design choices [1]

MÖNCH02

Full active chip (160 x 160 pixels) 5 pixel architectures (25 μm pitch) [1] Area: 4 x 4 mm<sup>2</sup>

2012

# The MÖNCH timeline



400 x 400 pixels, 25  $\mu$ m pitch  $\rightarrow$  1 cm<sup>2</sup> Best MÖNCH02 pixel design (Noise ≈ 31e<sup>-</sup> RMS) Spatial resolution (interpolated): 1–4 μm [2 - 5] Operated with high-Z sensors [6, 7]

 $2014 \rightarrow Today$ 

# ARE MÖNCH04 **HERE**

400 x 400 pixels, 25  $\mu$ m pitch  $\rightarrow$  1 cm<sup>2</sup> 19 pixel designs for synchrotron and XFEL applications

High testability of architectures and components  $2018 \rightarrow Today$ 

MÖNCH1.0

Optimized pixel architectures MÖNCH for synchrotron, for XFEL, or for both? Maximum single chip area: 2 x 3 cm<sup>2</sup> Module: 2 readout chips on a single detector

MÖNCH05 before MÖNCH1.0?

SOON?

# MONCH at Synchrotrons...

Exploiting the low noise for single photon detection capabilities

Fast frame rates with large duty cycle. Single photon detection capabilities with high DQE and highest spatial resolution

#### **Soft X-ray applications**

Detection of single low energy photons (< 1 keV)

#### **High-resolution imaging**

Spatial resolution of a few micrometers with interpolation algorithms

- Spectrometry [2]
- G2-less grating interferometry [3]

#### **Energy resolved imaging**

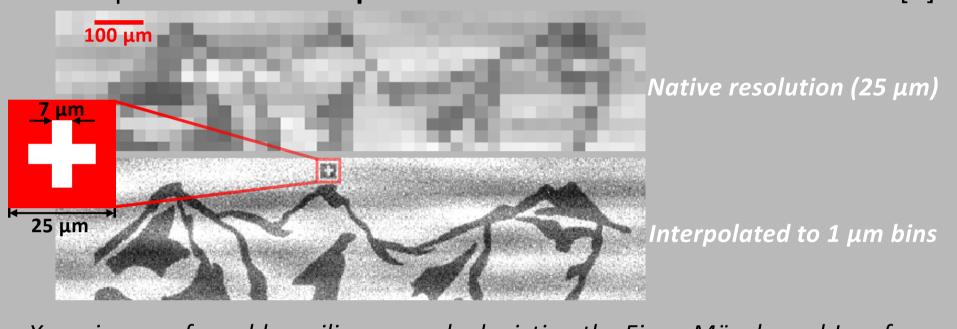
Combination of spectroscopy and imaging for X-ray applications with polychromatic beams [2]

- Laue diffraction
- Color imaging (K-edge subtraction, material discrimination)

# High-resolution imaging

Charge sharing over several pixels can increase resolution (cluster size depends on photon energy; sensor material, bias, and thickness)

**Position interpolation** algorithm based on  $\eta$  algorithm: sub-division into virtual pixels to achieve spatial resolutions of a few micrometers [5]



X-ray image of a gold on silicon sample depicting the Eiger, Mönch, and Jungfrau mountains acquired with MÖNCH03 at 10 keV [7]

But limited pixel area for resources, very large amount of data, and challenging bump bonding

# ...and for XFELs

WE

Exploiting the charge integrating architectures

Very short exposure times with time for readout

Charge integration of multiple soft X-ray photons (up to 200 x 12 keV ph/pix/frame)

Spatial resolution will be limited to the pixel pitch which is an

improvement from the other available XFEL detectors: **ePix100: 50 μm** [8] (*LCLS, Eu-XFEL*)

Jungfrau: 75 µm [9] (SwissFEL, Eu-XFEL, LCLS, PAL-XFEL)

**AGIPD: 200 μm** [10] (*Eu-XFEL*) **DSSC: 204 x 236 μm<sup>2</sup>** [11] (*Eu-XFEL*)

Large Pixel Detector: 500 µm [12] (Eu-XFEL)

**Dynamic Gain Switching (DGS) (dynamic range increase), and** overvoltage protection required

# Implemented MONCH04 pixel features

## Preamp

## Synchrotron applications

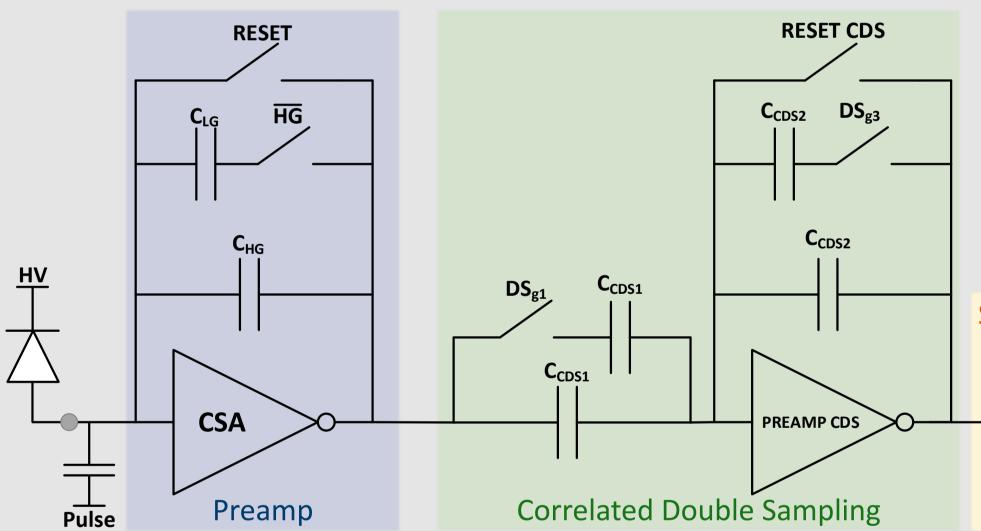
- Charge Sensitive Amplifiers (CSA) with static gain selection (+1 source follower design)
- Different feedback capacitor values tested
- "Stripped" variants with super high gain (and additional filtering) XFEL applications
- CSA optimized for Dynamic Gain Switching (two variants)
- Overvoltage protection circuit (not showed)
- Pixels with preamp pre-charging capabilities for testing

# **Correlated Double Sampling (CDS)**

- Static gain selection (x1, x2, x4); doubled for super high gain pixels
- 2 pixel designs with passive CDS, and 2 designs without CDS stage
- CDS stage bypass available on most designs for testing

# 19 pixel designs

9 designs for synchrotron 13 designs with 200 x 50 pixels 6 designs with 200 x 25 pixels 10 designs for FEL



## **Storage cells**

- Different capacitor technologies tested
  - MMC: high linearity, precise, low sensitivity to temperature, no leakage, poor capacitance density
  - NCAP: non-linear behavior (capacitance ∝ voltage), leakage depends on gate oxide thickness, higher capacitance density
- Different capacitance and capacity density tested
- Pixels contain 2 or 5 capacitors, each individually addressable
- Pre-charging available for storage cells and output buffer testing

## Storage cells **STORE** Column Pixel output buffer

## **Output buffer**

- Source follower output buffer
- Testing possible through storage cell pre-charging feature
- One pixel architecture without SF for charge readout

#### **Noise** 21.7 e RMS amplitude [arb.] MÖNCH03 design [HG-G4] LG capacitor x3.7 [HG-G4] $\sigma = 35.49 \pm 1.08 e^{-}$ RMS Super High Gain (SHG) [(S)HG-G8] $\sigma = 26.72 \pm 0.97 e^{-}$ RMS $\sigma = 22.75 \pm 0.74 e^{-}$ RMS Stripped SHG + filter [G8] $\sigma = 21.70 \pm 0.71 \,\mathrm{e^-}$ RMS 0.2 35 Noise [e<sup>-</sup> RMS]

# Preliminary characterisation results

Spectral response (2 x 2 clusters) MÖNCH03 design [HG-G4] LG capacitor x3.7 [HG-G4] Super High Gain (SHG) [(S)HG-G8] Stripped SHG [G8] amplitude [arb.] Stripped SHG + filter [G8] Normalised of O 20 25 Energy [keV]

#### Dark current in different storage capacitor technologies Temperature ≈ 18 °C $\longrightarrow$ MMC: $\Delta_{Pedestal} = \sqrt{(3.51e+07 \cdot t)}$ NCAP: $\Delta_{Pedestal} = \sqrt{(4.71e+07 \cdot t)}$ [ADU 4000 MMC + NCAP: $\Delta_{Pedestal} = \sqrt{(4.11e+07 \cdot t)}$ <sup>b</sup><sub>e</sub> 2000 $10^{-5}$ $10^{-1}$ $10^{0}$ $10^{-6}$ $10^{-4}$ $10^{-3}$

# **MÖNCH04** Testing

- Architectures characterisation
  - Additional testing of the presented synchrotron designs (incl. CSA, CDS)
  - XFEL designs to be tested
    - Biasing optimisation and timing implementation
    - Full characterisation with soft X-ray and laser
    - DGS architectures comparison
- Noise sources investigation and optimisation (on-chip and on-board)
- Alternative storage cell usage investigation (e.g. multi-sampling, noise mitigation)

[1] R. Dinapoli et al., (2014) "MÖNCH, a small pitch, integrating hybrid pixel detector for X-ray applications", JINST 9, C05015

[3] A. Bergamaschi et al., (2015) "Looking at single photons using hybrid detectors", JINST 10, C01033

[4] S Cartier et al., (2016) "Micrometer-resolution imaging using MÖNCH", J. Synchrotron Rad. 23, 1462–1473

[5] M. Ramilli et al., (2017) "Measurements with MÖNCH, a 25 μm pixel pitch hybrid pixel detector", JINST 12, C01071

[2] A. Bergamaschi et al., (2018) "The MÖNCH Detector for Soft X-ray, High-Resolution, and Energy Resolved Applications", Synchrotron Radiation News 31:6, 11-15

# The journey ahead of us

## Chip design

- Selection of the optimal design and components to implement
- Design of MÖNCH05 to validate/refine the pixel architectures? One architecture for synchrotron and one for XFEL?
- Design of MÖNCH1.0
  - Up to 2 x 3 cm<sup>2</sup>, at least 1 side-buttable
  - Implementation of the optimised pixel
  - Improved periphery for better performance and on-chip additions to reduce number of wirebonds

## **Detector technology development**

- Soft X-ray
  - Use and testing of sensors with thin entrance window

Time after pre-charging to 0 V [s]

- Poster by M. Carulla, 27/06
- Detection of softer X-rays with LGADs/iLGADs
- > Talk by J. Zhang, 29/06 @14:00, and poster by M. Carulla, 27/06

## Hard X-ray

 High-Z sensors characterisation and spatial resolution investigation

## References

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- [9] A. Mozzanica et al., (2016) "Characterization results of the JUNGFRAU full scale readout ASIC", JINST 11, C02047 [10] A. Allagholi et al., (2015) "AGIPD, a high dynamic range fast detector for the European XFEL", JINST 12, P12003
- [11] M. Porro et al., (2012) "Development of the DEPFET Sensor With Signal Compression: A Large Format X-Ray Imager With Mega-Frame Readout Capability for the European XFEL", IEEE TNS 59:6, 3339-3351 [6] S. Chiriotti et al., (2022) "High-spatial resolution measurements with a GaAs:Cr sensor using the charge integrating MÖNCH detector with a pixel pitch of 25 μm", JINST 17, P04007
- - [12] M.C. Veale et al., (2017) "Characterisation of the high dynamic range Large Pixel Detector (LPD) and its use at X-ray free electron laser sources", JINST 12, P12003